

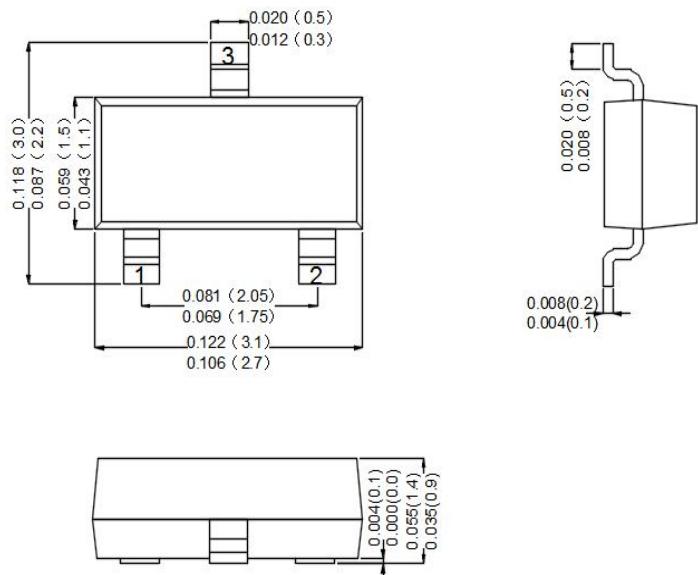


Features

- For general AF applications
- High collector current
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BC808 (PNP)

Mechanical Data

- Case:Molded Plastic,SOT-23
- Epoxy:UL 94V-0 rate flame retardant
- Terminals:Plated Leads Solderable perMIL-STD-750,Method-2026.
- Marking: BC818-16:6E; BC818-25:6F; BC818-40:6G
- Mounting Position : Any.
- Equivalent Circuit:



Dimensions in inches and (millimeters)

Maximum Ratings Maximum Ratings (Rating at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Units
Collector-Base Voltage	V_{CBO}	30	V
Collector-Emitter Voltage	V_{CEO}	25	V
Emitter-Base Voltage	V_{EBO}	5	V
Collector Current -Continuous	I_c	0.5	A
Collector Power Dissipation	P_c	0.3	W
Junction Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55-150	°C



Electrical Characteristics (Rating at 25°C ambient temperature unless otherwise specified.)

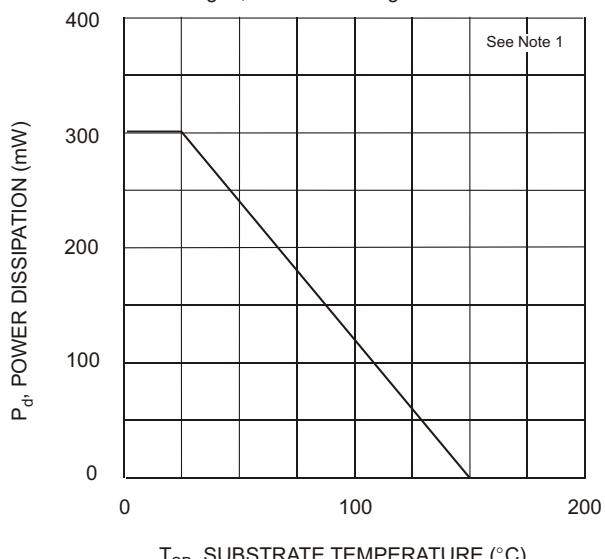
Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	V _{CBO}	I _C = 10µA, I _E =0	30			V
Collector-emitter breakdown voltage	V _{CEO}	I _C = 10mA, I _B =0	25			V
Emitter-base breakdown voltage	V _{EBO}	I _E = 1µA, I _C =0	5			V
Collector cut-off current	I _{CBO}	V _{CB} = 45 V, I _E =0			0.1	µA
Emitter cut-off current	I _{EBO}	V _{EB} = 4V, I _C =0			0.1	µA
DC current gain	h _{FE(1)}	V _{CE} = 1V, I _C = 100mA	100		600	
	h _{FE(2)}	V _{CE} = 1V, I _C = 500mA	40			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 500mA, I _B = 50mA			0.7	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C = 500mA, I _B = 50mA			1.2	V
Base-emitter voltage	V _{BE}	V _{CE} = 1 V, I _C = 500mA			1.2	V
Collector capacitance	C _{ob}	V _{CB} =10V, f=1MHz		10		pF
Transition frequency	f _T	V _{CE} = 5 V, I _C = 10mA f=100MHz	100			MHz

CLASSIFICATION OF h_{FE} (1)

Rank	BC818-16	BC818-25	BC818-40
Range	100-250	160-400	250-600
Marking	6E	6F	6G

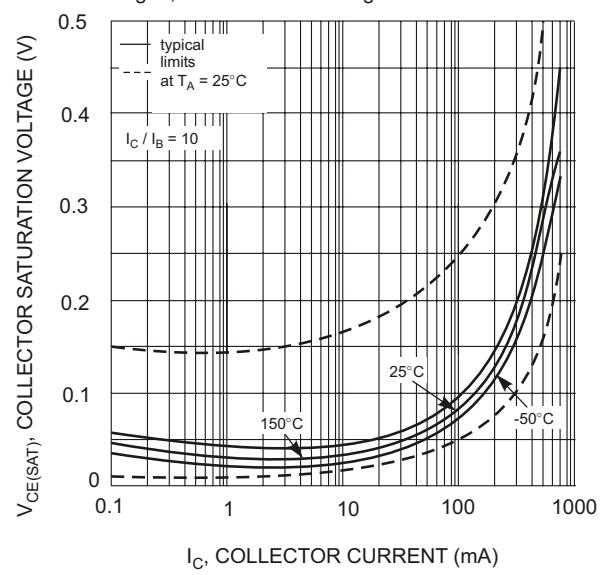
Rating And Characteristic Curves

Fig. 1, Power Derating Curve



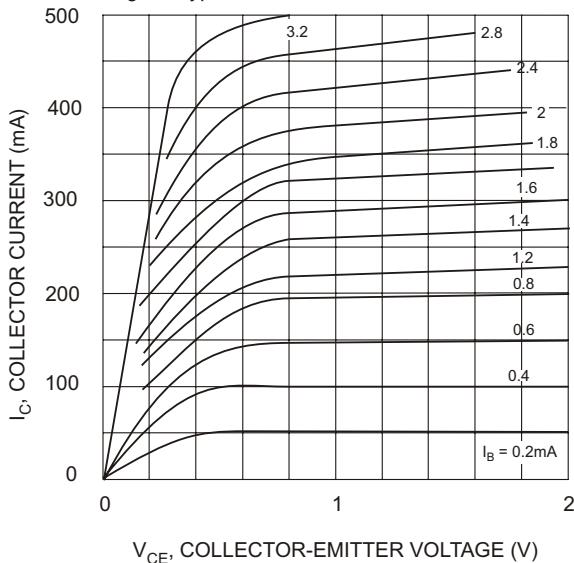
T_{SB} , SUBSTRATE TEMPERATURE (°C)

Fig. 3, Collector Sat. Voltage vs Collector Current



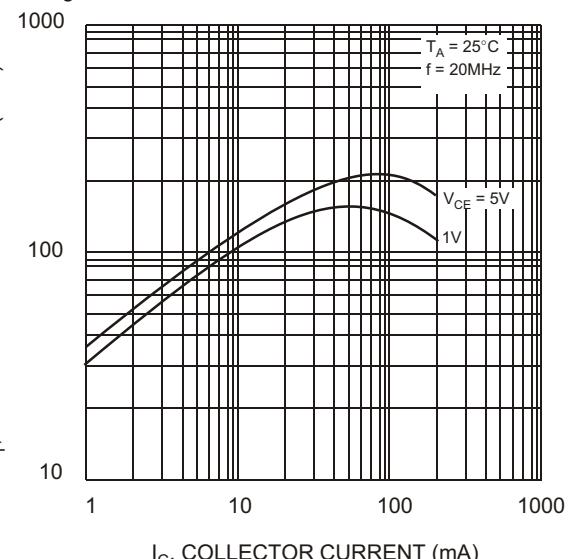
I_C , COLLECTOR CURRENT (mA)

Fig. 5, Typical Emitter-Collector Characteristics



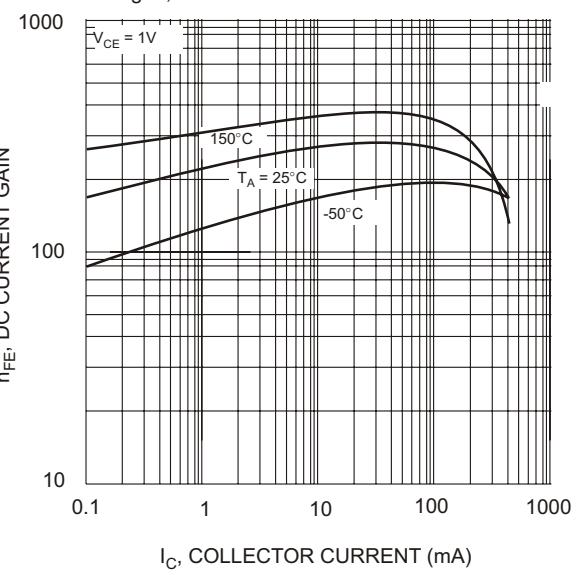
V_{CE} , COLLECTOR-EMITTER VOLTAGE (V)

Fig. 2, Gain-Bandwidth Product vs Collector Current



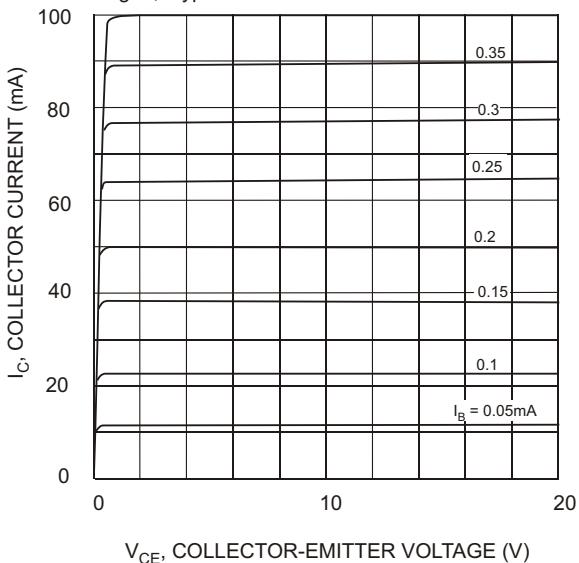
I_C , COLLECTOR CURRENT (mA)

Fig. 4, DC Current Gain vs Collector Current



I_C , COLLECTOR CURRENT (mA)

Fig. 6, Typical Emitter-Collector Characteristics



V_{CE} , COLLECTOR-EMITTER VOLTAGE (V)



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